Chipsmall

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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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DIODES
INCORPORATED®

Lead-free Green

AL5802

30V, ADJUSTABLE CURRENT SINK LINEAR LED DRIVER

Description

The AL5802 combines a high gain NPN transistor with a pre-biased NPN transistor to make a simple small footprint LED driver.

The LED current is set by an external resistor connected from REXT pin (6) to GND pin (4), the internal high gain transistor develops approximately 0.6V across the external resistor.

The AL5802 open-collector output can operate from 0.8V to 30V enabling it to operate from 5V to 24V power supplies without additional components.

PWM dimming of the LED current can be achieved by either driving the BIAS pin (2) with a low impedance voltage source, or driving the EN pin (3) with an external open-collector NPN transistor or open-drain N-channel MOSFET.

The AL5802 is available in a SOT26 package and is ideal for driving 20mA to 120mA LED currents.

Pin Assignments

**(Top View)**
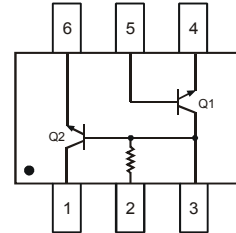
SOT26

Features

- Reference voltage VRSET = 0.65V
- -40 to +125°C temperature range
- 0.8V to 30V open-collector output
- Negative temperature co-efficient – automatically reduces the LED current at high temperatures
- Low thermal impedance SOT26 with copper leadframe
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Applications

- Linear LED driver
- LED signs
- Offline LED luminaries

Typical Application Circuit
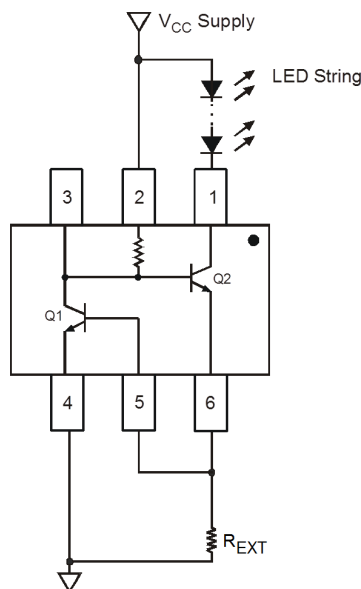
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

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Pin Descriptions

| Pin Number	Name	Function
1	OUT	Open-collector LED driver output
2	BIAS	Biases the open collector output transistor
3	EN	Enable pin for PWM dimming. Provides access to the base of Q2 and collector of Q1
4	GND	Ground reference point for setting LED current
5	FB	Feedback pin. Should be connected to pin 6.
6	REXT	Current sense pin. LED current sensing resistor should be connected from here to GND.

Functional Block Diagram
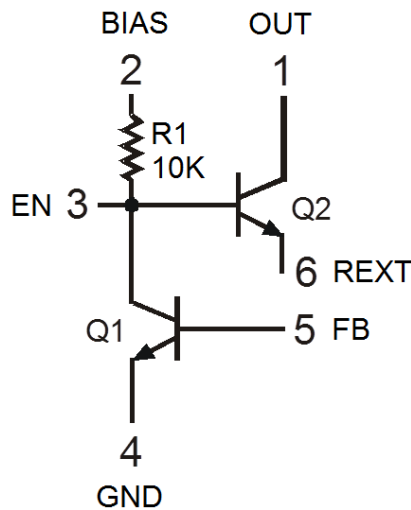
Fig. 1 Block Diagram

Absolute Maximum Ratings

Symbol	Characteristics	Values	Unit
V_{OUT}	Output voltage relative to GND	30	V
V_{BIAS}	BIAS voltage relative to GND (Note 4)	30	V
V_{FB}	LED voltage relative to GND	6	V
V_{EN}	EN voltage relative to GND	6	V
V_{REXT}	REXT voltage relative to GND	6	V
I_{OUT}	Output current	150	mA
T_J	Operating junction temperature	-40 to +150	°C
T_{ST}	Storage temperature	-55 to +150	°C

These are stress ratings only. Operation outside the absolute maximum ratings may cause device failure.
Operation at the absolute maximum rating for extended periods may reduce device reliability.

Note: 4. With pins 5 and 6 connected together.

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Package Thermal Data

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) @ T_A = +25°C Power Dissipation (Note 6) @ T_A = +25°C Power Dissipation (Note 7) @ T_A = +25°C	P_D	0.37 0.87 1	W
Thermal Resistance, Junction to Ambient Air (Note 5) @ T_A = +25°C Thermal Resistance, Junction to Ambient Air (Note 6) @ T_A = +25°C Thermal Resistance, Junction to Ambient Air (Note 7) @ T_A = +25°C	$R_{\theta JA}$	335 143 120	°C/W

Notes: 5. Device mounted on FR-4 PCB, 2oz with minimum recommended pad layout.
6. Device mounted on 25mm x 25mm 2oz copper board.
7. Device mounted on 50mm x 50mm 2oz copper board.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{BIAS}	Supply voltage range	4.5	30	V
V_{OUT}	OUT voltage range	0.8	30	
I_{LED}	LED pin current (Note 8)	10	120	mA
T_A	Operating ambient temperature range	-40	+125	°C

Note: 8. Subject to ambient temperature, power dissipation and PCB.

Electrical Characteristics – NPN Transistor – Q1 (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic	Test Condition	Min	Typ	Max	Unit
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (Note 9)	I_C = 1.0mA, I_B = 0	40	—	—	V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10µA, I_C = 0	6.0	—	—	V
I_{CEX}	Collector Cutoff Current	V_{CE} = 30V, $V_{EB(OFF)}$ = 3.0V	—	—	50	nA
I_{BL}	Base Cutoff Current	V_{CE} = 30V, $V_{EB(OFF)}$ = 3.0V	—	—	50	nA
h_{FE}	DC Current Gain	I_C = 100µA, V_{CE} = 1.0V I_C = 1.0mA, V_{CE} = 1.0V I_C = 10mA, V_{CE} = 1.0V	40 70 100	— — —	— — 300	—
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage (Note 9)	I_C = 10mA, I_B = 1.0mA	—	—	0.20	V
$V_{BE(SAT)}$	Base-Emitter Saturation Voltage	I_C = 10mA, I_B = 1.0mA	0.65	—	0.85	V

Electrical Characteristics – NPN Pre-biased Transistor – Q2 (@T_A = +25°C, unless otherwise specified.)

Symbol	Characteristic	Test Condition	Min	Typ	Max	Unit
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 50µA, I_E = 0	30	—	—	V
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (Note 9)	I_C = 1mA, I_B = 0	30	—	—	V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 50µA, I_C = 0	5.0	—	—	V
I_{CBO}	Collector Cut-Off Current	V_{CB} = 30V, I_E = 0	—	—	0.5	µA
I_{EBO}	Emitter Cut-Off Current	V_{EB} = 4V, I_C = 0	—	—	0.5	µA
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage (Note 9)	I_C = 10mA, I_B = 1mA	—	—	0.3	V
h_{FE}	DC Current Gain (Note 9)	V_{CE} = 5V, I_C = 150mA	100	—	—	—
R_1	Input Resistance	—	7	10	13	kΩ

*Characteristics of transistor only.

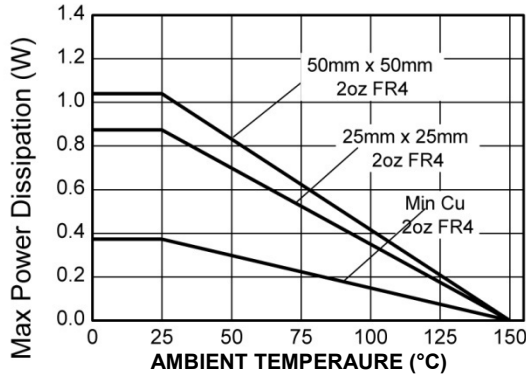Note: 9. Short duration pulse test used to minimize self-heating effect.

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Thermal Characteristics

Fig. 2 Derating Curve
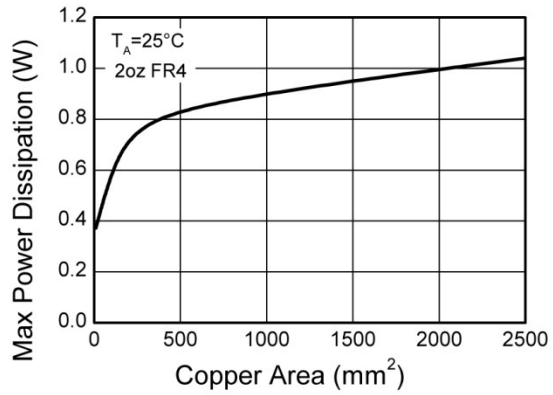
Fig. 3 Max Power vs. Area

Fig. 4 Thermal Resistance vs. Area

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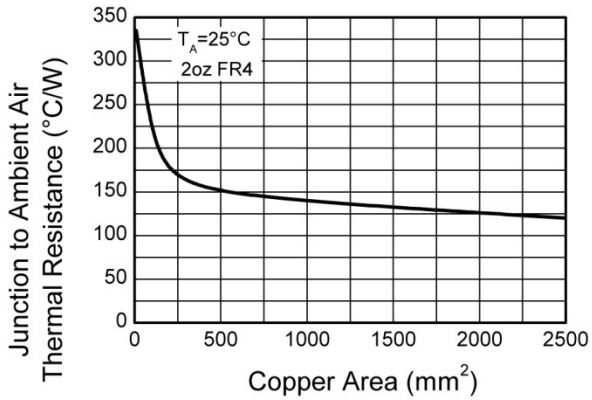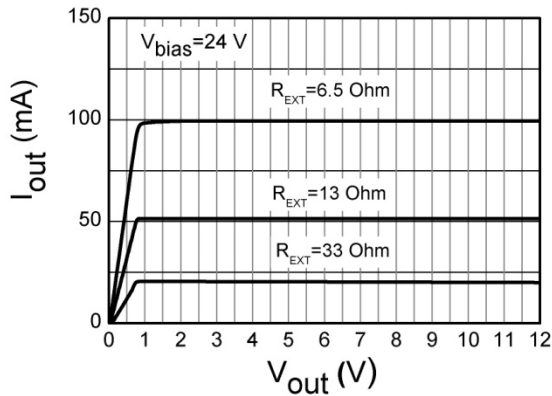
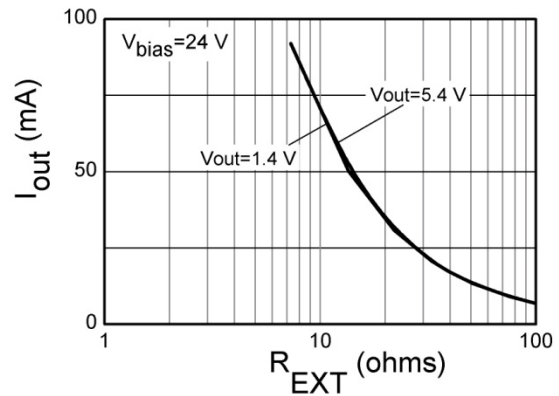## Typical Performance Characteristics

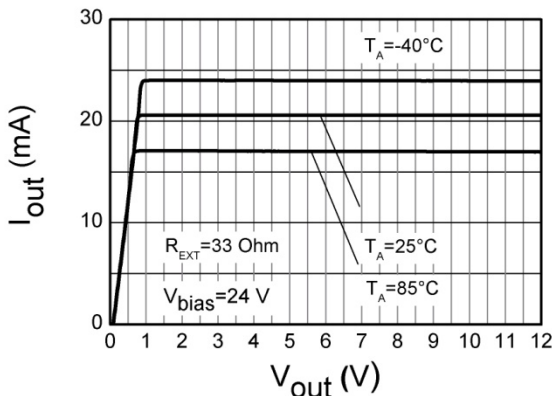Fig. 5 Output Current vs. V_out

Fig. 6 Output Current vs. R_EXT

Fig. 7 Output Current vs. V_out

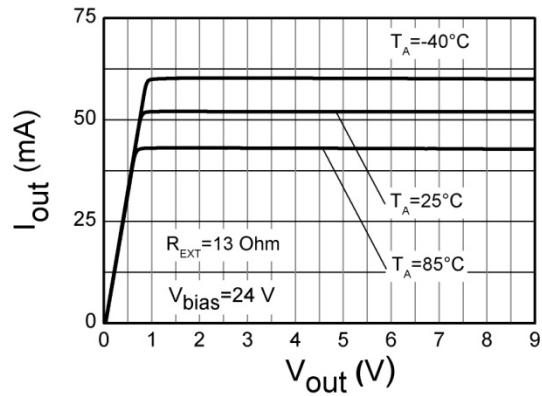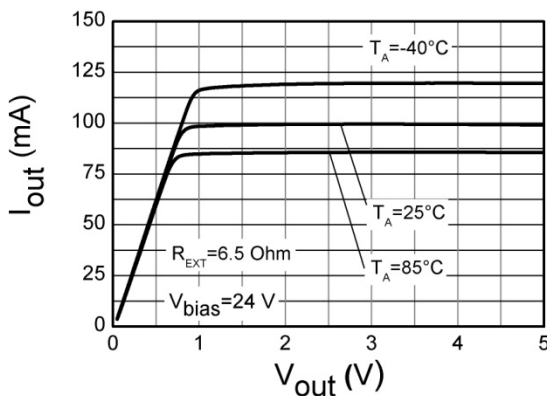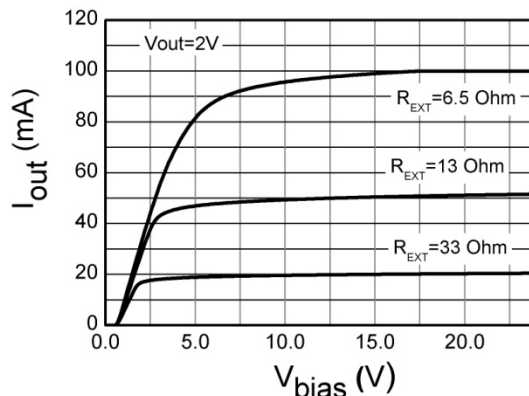Fig. 8 Output Current vs. V_out

Fig. 9 Output Current vs. V_out

Fig. 10 Output Current vs. V_bias

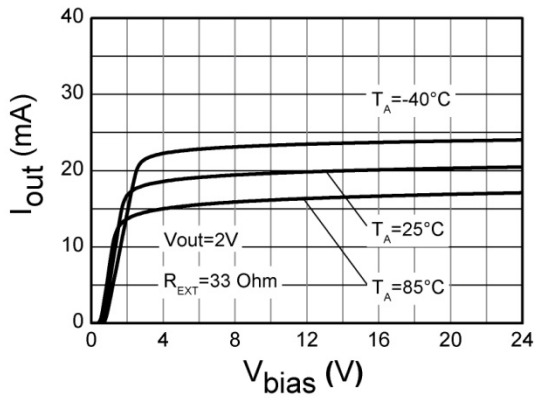Note: 10. V_{out} in the "Output current Vs V_{out}" graphs limited by power dissipation in the device.

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Fig. 11 Output Current vs. V_bias
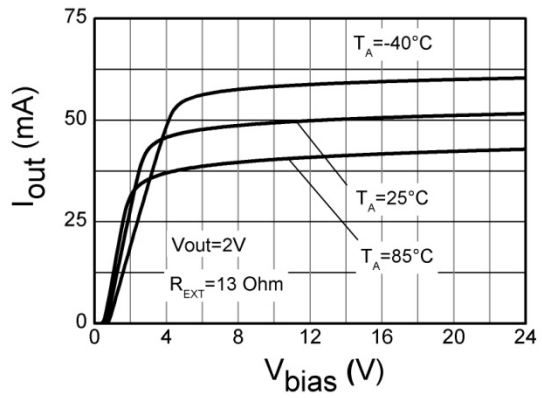
Fig. 12 Output Current vs. V_bias

Fig. 13 Output Current vs. V_bias

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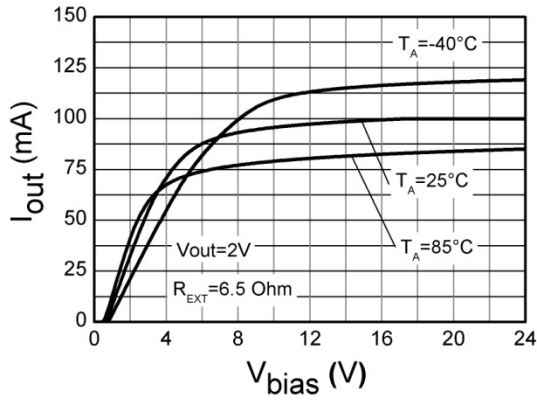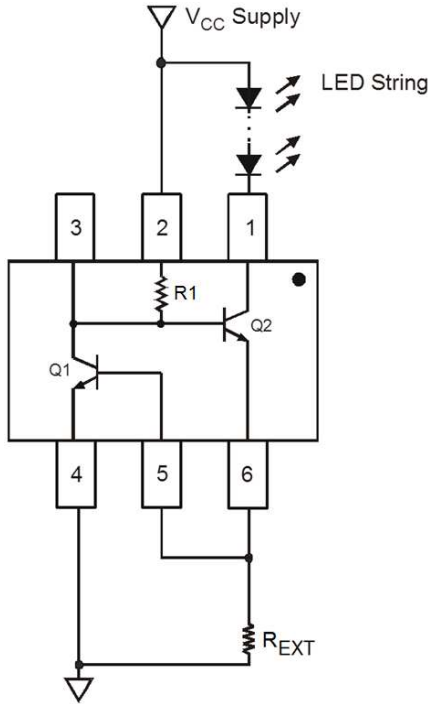
Application Information

Fig. 14 Typical Application Circuit for
Linear Mode Current Sink LED Driver

The AL5802 has been designed for driving low current LEDs with typical LED current of 20mA to 100mA. It provides a cost effective way for driving low current LEDs compared with more complex switching regulator solutions. Furthermore, it reduces the PCB board area of the solution as there is no need for external components like inductors, capacitors and switching diodes.

Figure 14 shows a typical application circuit diagram for driving an LED or string of LEDs. The NPN transistor Q1 measures the LED current by sensing the voltage across an external resistor R_{EXT}. Q1 uses its V_{BE} as reference to set the voltage across R_{EXT} and controls the base current into Q2. Q2 operates in linear mode to regulate the LED current. The LED current is

$$I_{LED} = V_{BE(Q1)} / R_{EXT}$$

From this, for any required LED current the necessary external resistor R_{EXT} can be calculated from

$$R_{EXT} = V_{BE(Q1)} / I_{LED}$$

Two or more AL5802 can be connected in parallel to construct higher current LED strings as shown in Figure 15.

Consideration of the expected linear mode power dissipation must be factored into the design, with respect to the AL5802's thermal resistance. The maximum voltage across the device can be calculated by taking the maximum supply voltage less the voltage across the LED string.

$$V_{CE(Q2)} = V_{CC} - V_{LED} - V_{BE(Q1)}$$
$$P_D = V_{CE(Q2)} * I_{LED} + (V_{CC} - V_{BE(Q2)} - V_{BE(Q1)})^2 / R_1$$

As the output current of AL5802 increases, it is necessary to provide appropriate thermal relief to the device. The power dissipation supported by the device is dependent upon the PCB board material, the copper area and the ambient temperature. The maximum dissipation the device can handle is given by:

$$P_D = (T_{J(MAX)} - T_A) / R_{\theta JA}$$

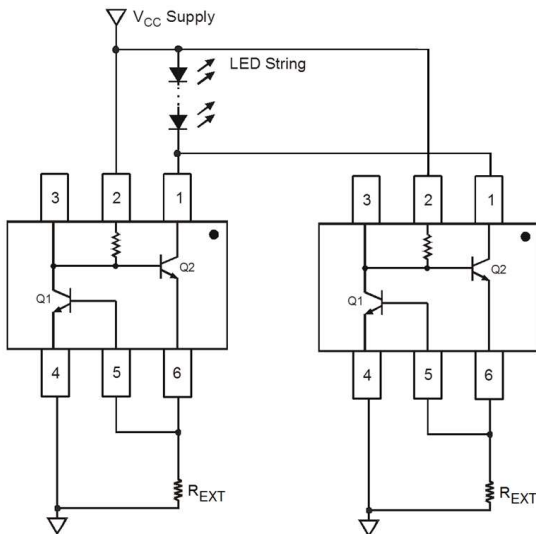Refer to the thermal characteristic graphs on page 4 for selecting the appropriate PCB copper area.

Fig. 15 Application Circuit for Increasing LED Current

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PWM dimming can be achieved by driving the EN pin. An external open-collector NPN transistor or open-drain N-channel MOSFET can be used to drive the EN pin as shown in Figure 16. Dimming is achieved by turning the LEDs ON and OFF for a portion of a single cycle. The PWM signal can be provided by a micro-controller or analog circuitry. Figure 17 is a typical response of LED current vs. PWM duty cycle on the EN pin.

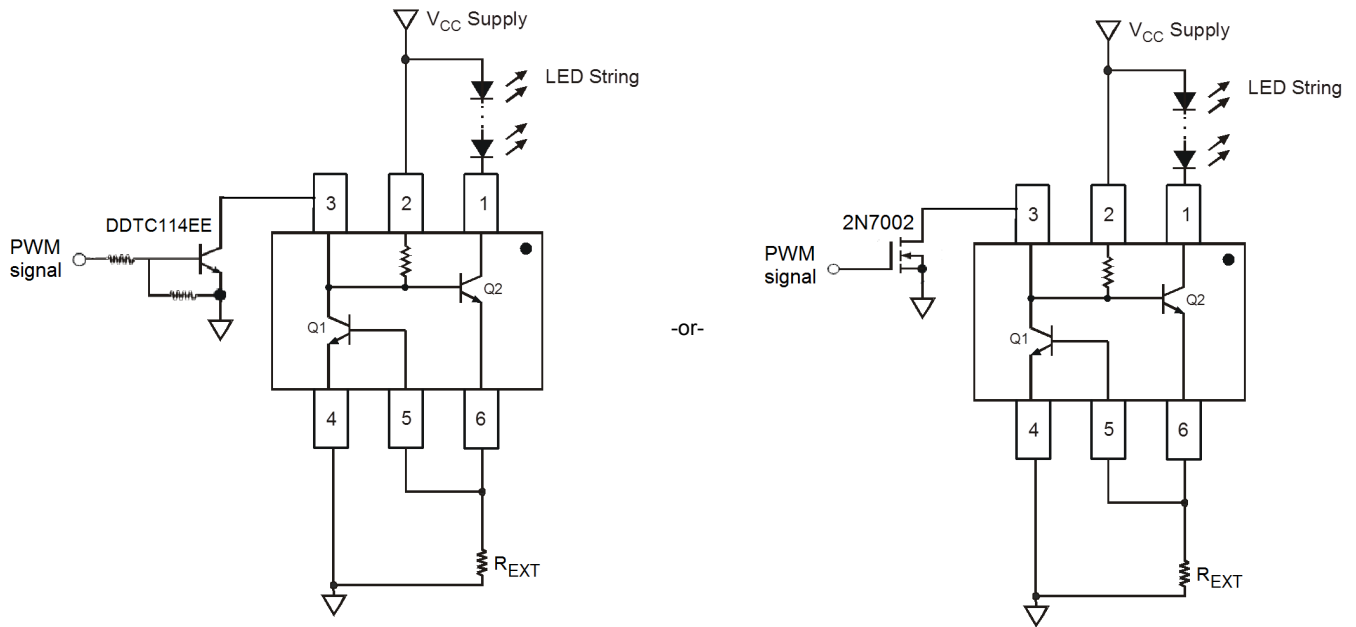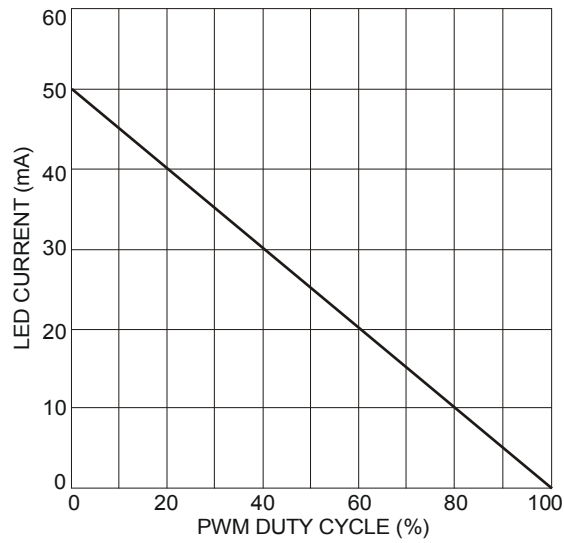Fig. 16 Application Circuits for LED Driver with PWM Dimming Functionality

Fig. 17 Typical LED current response vs. PWM duty cycle for
R_{EXT} = 13Ω at 400Hz PWM frequency

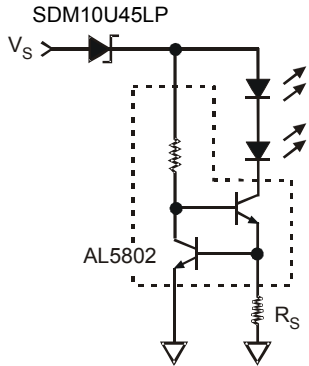AL5802
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Fig. 18 Application circuit for LED driver
with reverse polarity protection

Fig. 19 Application circuit for LED driver with
assured operation regardless of polarity

To remove the potential of incorrect connection of the power supply damaging the lamp's LEDs, many systems use some form of reverse polarity protection.

One solution for reverse input polarity protection is to simply use a diode with a low V_F in-line with the driver/LED combination. The low V_F increases the available voltage to the LED stack and dissipates less power. A circuit example is presented in Fig. 18 using Diodes Inc. SBR® (Super Barrier Rectifier) technology. An SDM10U45LP (0.1A/45V) is shown, providing exceptionally low V_F for its package size of 1mm x 0.6mm, equivalent to an 0402 chip style package. Other reverse voltage ratings are also available in Diodes' website such as the SBR02U100LP (0.2A/100V) or SBR0220LP (0.2A/20V).

Automotive applications commonly use this method for reverse battery protection.

A second approach, shown in Fig. 19, improves upon the method shown in Fig. 18. Whereas the method in Fig. 18 protects the light engine, it will not function until the problem has been diagnosed and corrected.

The method shown in Fig. 19 not only provides reverse polarity protection, it also corrects the reversed polarity, allowing the light engine to function.

The BAS40BRW incorporates four low V_F, Schottky diodes into a single package and allows more voltage available for the LED stack and dissipates less power that standard rectifier bridges.
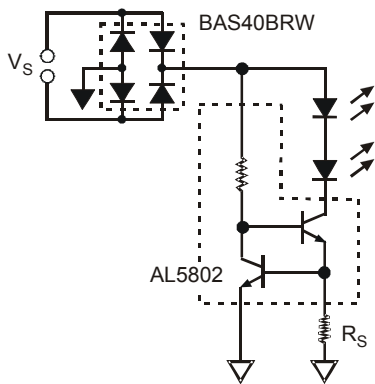
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Ordering Information (Note 11)

Device	Qualification	Packaging	Tape and Reel	
			Quantity	Part Number Suffix
AL5802	Commercial	SOT26	3,000/Tape & Reel	-7
AL5802	Commercial	SOT26	10,000/Tape & Reel	-13

Note: 11. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

L102   YM
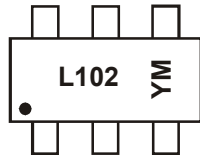
L102 = Product Type Marking Code
YM = Date Code Marking
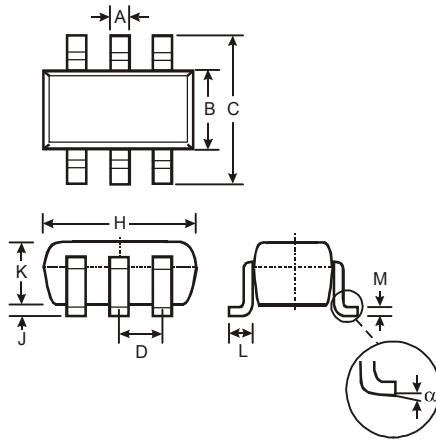Y = Year (ex: B = 2014)
M = Month (ex: 9 = September)

Date Code Key

Year	2011	2012	2013	2014	2015	2016	2017	2018	2019
Code	Y	Z	A	B	C	D	E	F	G

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.
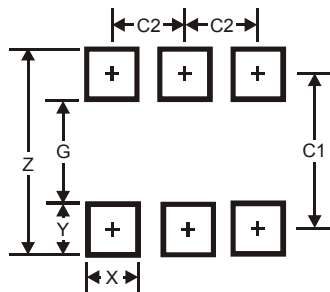
Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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